



Vishay Siliconix

COMPLIANT

HALOGEN FREE

N-Channel 20-V (D-S) MOSFET

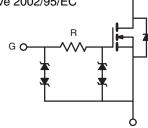
PRODUCT SUMMARY									
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A) ^a	Q _g (Typ.)						
20	0.030 at V _{GS} = 4.5 V	9							
	0.041 at V _{GS} = 2.5 V	9	6 nC						
	0.057 at V _{GS} = 1.8 V	9	0110						
	0.082 at V _{GS} = 1.5 V	5							

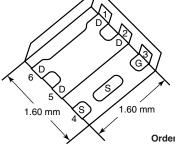
FEATURES

- Halogen-free According to IEC 61249-2-21 **Definition**
- TrenchFET® Power MOSFET
- New Thermally Enhanced PowerPAK® SC-75 Package
 - Small Footprint Area
 - Low On-Resistance
 - Thin 0.75 mm Profile
- Typical ESD Protection 4000 V
- 100 % R_q Tested
- Compliant to RoHS Directive 2002/95/EC

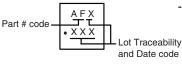
APPLICATIONS Portable Devices

- Load Switch
- Battery Switch





PowerPAK SC-75-6L-Single



Marking Code

Ordering Information: SiB422EDK-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	5 T _A = 25 °C, unle	ess otherwis	e noted		
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	± 8	V	
	T _C = 25 °C		9 ^a		
Continuous Drain Current (T _J = 150 °C)	T _C = 70 °C	1 .	9 ^a	7	
Continuous Diain Current (1) = 150 C)	T _A = 25 °C	l _D	7.1 ^{b, c}		
	T _A = 70 °C		5.7 ^{b, c}	Α	
Pulsed Drain Current	I _{DM}	25			
Continuous Source-Drain Diode Current	T _C = 25 °C	I-	9 ^a		
Continuous Source-Diam Diode Current	T _A = 25 °C	- I _S	2.1 ^{b, c}		
	T _C = 25 °C		13		
Maximum Power Dissipation	T _C = 70 °C	P _D	8.4	W	
Maximum Fower Dissipation	T _A = 25 °C	гD	2.5 ^{b, c}	VV	
	T _A = 70 °C		1.6 ^{b, c}		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature) ^{d, e}		260		

THERMAL RESISTANCE RATINGS										
Parameter		Symbol	Typical	Maximum	Unit					
Maximum Junction-to-Ambient ^{b, f}	t ≤ 5 s	R _{thJA}	41	51	°C/W					
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	7.5	9.5						

Notes:

- a. Package limited, $T_C = 25$ °C.
- b. Surface Mounted on 1" x 1" FR4 board.
- c. t = 5 s.
- d. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under Steady State conditions is 105 °C/W.

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted									
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit			
Static		<u> </u>				l			
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20			V			
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		18		m\//°C			
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	- I _D = 250 μA		- 2.5		mV/°C			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.4		1.0	V			
Gate-Source Leakage	lasa	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1.5				
Gale-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V			± 25				
Zero Gate Voltage Drain Current	lace	V _{DS} = 20 V, V _{GS} = 0 V			1	μΑ			
Zero Gate voltage Dialii Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 55 °C			10				
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	15			Α			
		$V_{GS} = 4.5 \text{ V}, I_D = 5 \text{ A}$		0.025	0.030				
	Ь	$V_{GS} = 2.5 \text{ V}, I_D = 4.3 \text{ A}$		0.034	0.041				
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 1.8 V, I _D = 1.5 A		0.046	0.057	Ω			
	I	V _{GS} = 1.5 V, I _D = 1 A		0.055	0.082				
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 5 A		28		S			
Dynamic ^b									
Total Cata Charge	0	$V_{DS} = 10 \text{ V}, V_{GS} = 8 \text{ V}, I_{D} = 7.1 \text{ A}$		11.5	18	nC			
Total Gate Charge	Q_g			6	9				
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 7.1 \text{ A}$		0.8					
Gate-Drain Charge	Q_{gd}			1.6					
Gate Resistance	R_{g}	f = 1 MHz	0.46	2.3	4.6	kΩ			
Turn-On Delay Time	t _{d(on)}			0.3	0.45				
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_{L} = 1.8 \Omega$		0.6	0.9				
Turn-Off DelayTime	t _{d(off)}	$I_D \cong 5.7 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		3.8	6				
Fall Time	t _f			1.7	2.6	110			
Turn-On Delay Time	t _{d(on)}			0.15	0.25	μs			
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_{L} = 1.8 \Omega$		0.3	0.45				
Turn-Off DelayTime	t _{d(off)}	$I_D \cong 5.7 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		5.6	9				
fall Time t _f				1.6	2.5				
Drain-Source Body Diode Characteristic	s								
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			9	Α			
Pulse Diode Forward Current	I _{SM}				25	A			
Body Diode Voltage	V _{SD}	I _S = 5.7 A, V _{GS} = 0 V		0.85	1.2	V			
Body Diode Reverse Recovery Time	t _{rr}			15	30	ns			
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = 5.7 A, dl/dt = 100 A/μs, T _{.I} = 25 °C		7.5	15	nC			
Reverse Recovery Fall Time	t _a	$\int_{1}^{1} \frac{1}{1} = 0.7 \text{ A}, \text{ al/at} = 100 \text{ A/} \mu \text{s}, \text{ f} = 25 \text{ C}$		8		ns			
•						no.			

Notes:

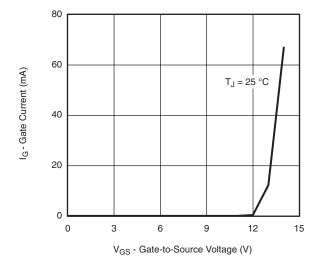
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

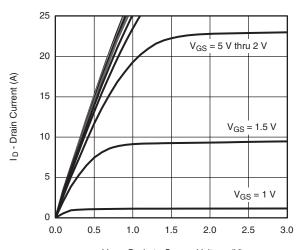


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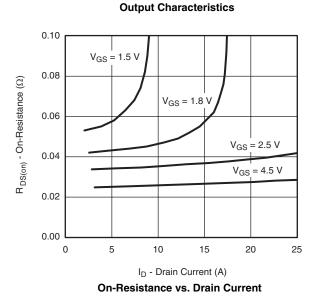
TYPICAL CHARACTERISTICS $T_A = 25~^{\circ}C$, unless otherwise noted



Gate Current vs. Gate-to-Source Voltage

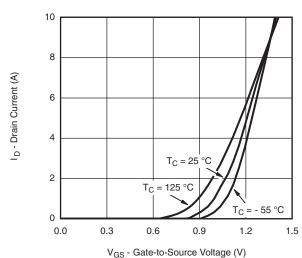


V_{DS} - Drain-to-Source Voltage (V)



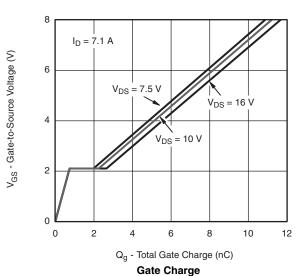
 $\begin{array}{c} 10^{-1} \\ 10^{-2} \\ 10^{-3} \\ 10^{-4} \\ 10^{-5} \\ 10^{-6} \\ 10^{-7} \\ 10^{-8} \\ 10^{-9} \\ 10^{-10} \\ 0 \\ 3 \\ 6 \\ 9 \\ 12 \\ 15 \\ V_{GS} - Gate-to-Source Voltage (V) \\ \end{array}$

Gate Current vs. Gate-to-Source Voltage



VGS - Gale-10-30uice vollage (V)

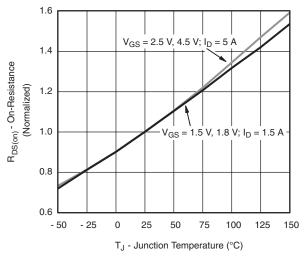
Transfer Characteristics



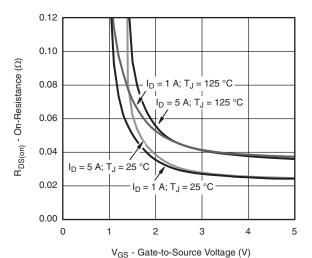
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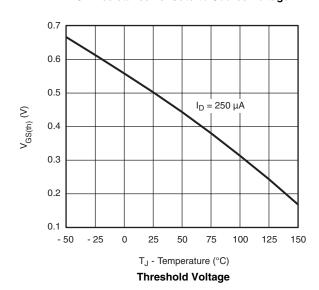
TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted

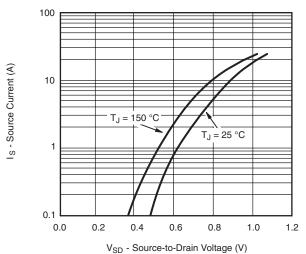


Normalized On-Resistance vs. Junction Temperature

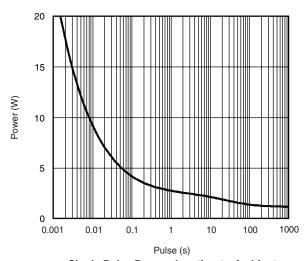


On-Resistance vs. Gate-to-Source Voltage

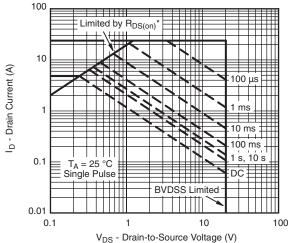




Source-Drain Diode Forward Voltage



Single Pulse Power, Junction-to-Ambient



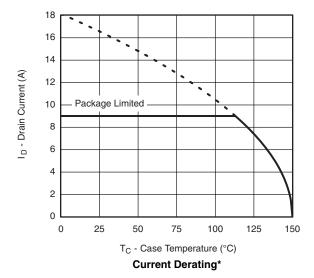
* V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

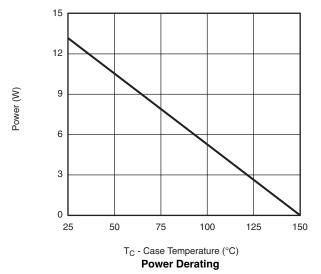
Safe Operating Area, Junction-to-Ambient



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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



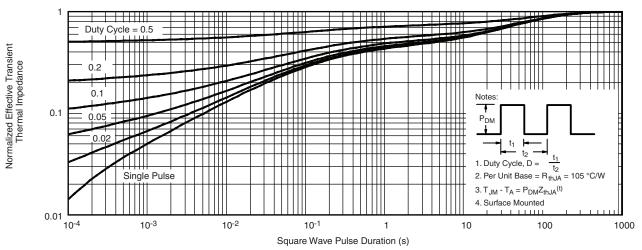


^{*} The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

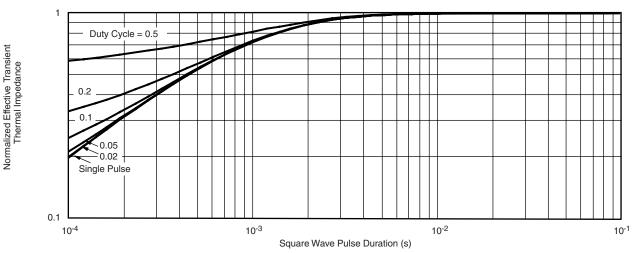
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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



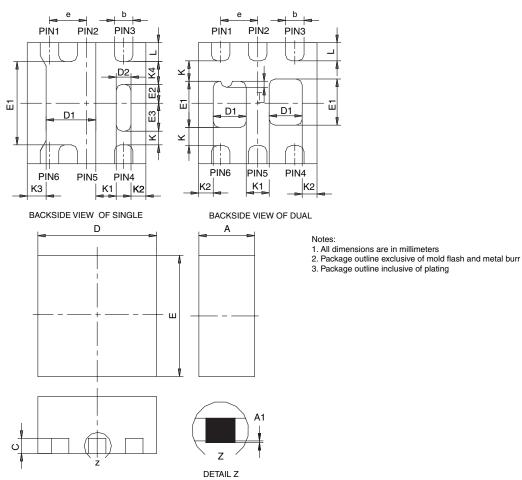
Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppq?65297.





PowerPAK® SC75-6L



			SINGL	E PAD			DUAL PAD					
DIM N		MILLIMETERS			INCHES		MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.18	0.25	0.33	0.007	0.010	0.013	0.18	0.25	0.33	0.007	0.010	0.013
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
D1	0.57	0.67	0.77	0.022	0.026	0.030	0.34	0.44	0.54	0.013	0.017	0.021
D2	0.10	0.20	0.30	0.004	0.008	0.012						
Е	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
E1	1.00	1.10	1.20	0.039	0.043	0.047	0.51	0.61	0.71	0.020	0.024	0.028
E2	0.20	0.25	0.30	0.008	0.010	0.012						
E3	0.32	0.37	0.42	0.013	0.015	0.017						
е		0.50 BSC 0.020 BSC			;	0.50 BSC			0.020 BSC			
K	0.180 TYP				0.007 TYP		0.245 TYP 0.010 TYP					
K1	0.275 TYP			0.011 TYP			0.320 TYP			0.013 TYP		
K2	0.200 TYP			0.008 TYP			0.200 BSC			0.008 TYP		
К3	0.255 TYP			0.010 TYP			•					
K4	0.300 TYP			0.012 TYP								
L	0.15	0.25	0.35	0.006	0.010	0.014	0.15	0.25	0.35	0.006	0.010	0.014
T							0.03	0.08	0.13	0.001	0.003	0.005

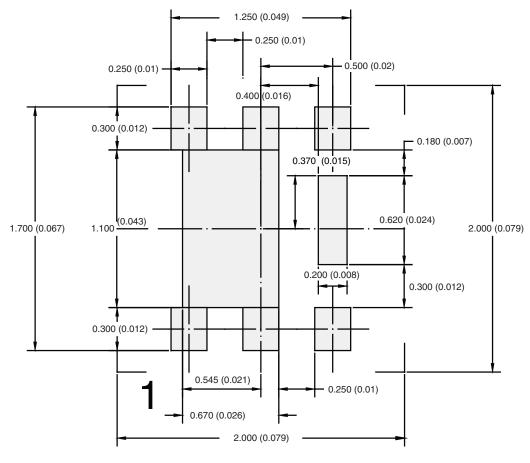
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DWG: 5935

Document Number: 73000 06-Aug-07



RECOMMENDED PAD LAYOUT FOR PowerPAK® SC75-6L Single



Dimensions in mm/(Inches)

Return to Index

ATTLICATION NOT





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